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April 1st, 2010 Renesas Electronics Corporation

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DATA SHEET



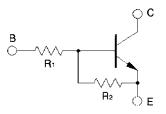
Phase-out/Discontinued BB1 SERIES

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

The BB1 Series is an N type small signal transistor and enables the reduction of component counts and downsizing of sets due to on-chip resistors. This transistor is especially ideal for use in household electronic appliances and OA equipments such as VCRs and TVs.

FEATURES

- Up to 0.7 A current drive available
- On-chip bias resistor
- · Low power consumption during drive

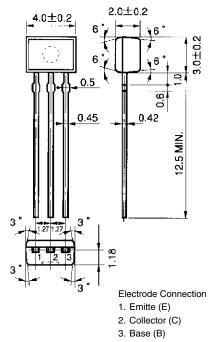


QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



BB1 SERIES LISTS

| Products | R1 (KΩ) | R₂ (KΩ) |
|----------|---------|---------|
| BB1A4A | _ | 10 |
| BB1L2Q | 0.47 | 4.7 |
| BB1A3M | 1.0 | 1.0 |
| BB1F3P | 2.2 | 10 |
| BB1J3P | 3.3 | 10 |
| BB1L3N | 4.7 | 10 |
| BB1A4M | 10 | 10 |

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Phase-out/Discontinued

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit |
|-----------------------------|-----------------|-------------|------|
| Collector to base volgate | Vсво | 30 | V |
| Colletor to emitter voltage | VCEO | 25 | V |
| Emitter to base voltage | VEBO | 10 | V |
| Collector current (DC) | IC(DC) | 0.7 | А |
| Collector current (Pulse) | C(pulse) Note 1 | 1.0 | А |
| Base current (DC) | B(DC) | 0.02 | А |
| Total power dissipation | Р⊤ | 250 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Note 1 PW \leq 10 ms, duty cycle \leq 50 %

BB1A4A

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | Vcb = 30 V, IE = 0 | | | 100 | nA |
| DC current gain | hfE1 ^{Note 2} | Vce = 2.0 V, Ic = 0.1 A | 300 | | | - |
| DC current gain | hfe2 ^{Note 2} | Vce = 2.0 V, Ic = 0.5 A | 300 | | | - |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | | | - |
| Collector saturation voltage | VCE(sat) Note 2 | Ic = 0.5 A, Iв = 5 mA | | 0.27 | 0.4 | V |
| Low level input voltage | VIL ^{Note 2} | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | R1 | | - | - | - | Ω |
| E-to-B resistance | R2 | | 7 | 10 | 13 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1L2Q ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | $V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$ | | | 100 | nA |
| DC current gain | hFE1 Note 2 | Vce = 2.0 V, Ic = 0.1 A | 150 | 400 | | - |
| DC current gain | hFE2 Note 2 | Vce = 2.0 V, Ic = 0.5 A | 300 | 700 | | - |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | 600 | | - |
| Low level output voltage | VOL ^{Note 2} | V _{IN} = 5.0 V, Ic = 0.5 A | | 0.2 | 0.3 | V |
| Low level input voltage | VIL ^{Note 2} | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | R1 | | 329 | 470 | 611 | Ω |
| E-to-B resistance | R2 | | 3.29 | 4.7 | 6.11 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1A3M ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | V _{CB} = 30 V, I _E = 0 | | | 100 | nA |
| DC current gain | hFE1 ^{Note 2} | Vce = 2.0 V, Ic = 0.1 A | 80 | | | - |
| DC current gain | hFE2 ^{Note 2} | Vce = 2.0 V, Ic = 0.5 A | 100 | | | - |
| DC current gain | hFE3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | | | - |
| Low level output voltage | VOL Note 2 | V _{IN} = 5.0 V, Ic = 0.5 A | | 0.3 | 0.4 | V |
| Low level input voltage | VIL ^{Note 2} | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | R1 | | 0.7 | 1.0 | 1.3 | kΩ |
| E-to-B resistance | R2 | | 0.7 | 1.0 | 1.3 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1F3P

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | $V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$ | | | 100 | nA |
| DC current gain | hfe1 ^{Note 2} | Vce = 2.0 V, lc = 0.1 A | 300 | | | - |
| DC current gain | hFE2 Note 2 | Vce = 2.0 V, Ic = 0.5 A | 300 | | | - |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | | | - |
| Low level output voltage | VOL ^{Note 2} | V _{IN} = 5.0 V, Ic = 0.3 A | | | 0.3 | V |
| Low level input voltage | VIL ^{Note 2} | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | Rı | | 1.54 | 2.2 | 2.86 | kΩ |
| E-to-B resistance | R2 | | 7 | 10 | 13 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BP1J3P

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|------------------------|-------------------------------|------|------|------|------|
| Collector cutoff current | Ісво | $V_{CB} = 30 V, I_E = 0$ | | | 100 | nA |
| DC current gain | hfE1 Note 2 | Vce = 2.0 V, Ic = 0.1 A | 300 | 600 | | _ |
| DC current gain | hfe2 ^{Note 2} | Vce = 2.0 V, Ic = 0.5 A | 300 | 700 | | - |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | 600 | | _ |
| Low level output voltage | VOL ^{Note 2} | $V_{IN} = 5.0 V$, Ic = 0.2 A | | 0.14 | 0.3 | V |
| Low level input voltage | VIL ^{Note 2} | Vcε = 5.0 V, lc = 100 μA | | | 0.3 | V |
| Input resistance | R1 | | 2.31 | 3.3 | 4.29 | kΩ |
| E-to-B resistance | R2 | | 7 | 10 | 13 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1L3N ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | $V_{CB} = 30 V, I_E = 0$ | | | 100 | nA |
| DC current gain | hfE1 ^{Note 2} | Vce = 2.0 V, Ic = 0.1 A | 300 | | | - |
| DC current gain | hfe2 ^{Note 2} | Vce = 2.0 V, Ic = 0.5 A | 300 | | | - |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | | | _ |
| Low level output voltage | VOL Note 2 | V _{IN} = 5.0 V, Ic = 0.2 A | | | 0.3 | V |
| Low level input voltage | VIL ^{Note 2} | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | Rı | | 3.29 | 4.7 | 6.11 | kΩ |
| E-to-B resistance | R2 | | 7 | 10 | 13 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1A4M

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|------------------------|--|------|------|------|------|
| Collector cutoff current | Ісво | $V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$ | | | 100 | nA |
| DC current gain | hfe1 ^{Note 2} | Vce = 2.0 V, Ic = 0.1 A | 300 | | | - |
| DC current gain | hFE2 ^{Note 2} | Vce = 2.0 V, Ic = 0.5 A | 300 | | | _ |
| DC current gain | hfe3 ^{Note 2} | Vce = 2.0 V, Ic = 0.7 A | 135 | | | - |
| Collector saturation voltage | VOL ^{Note 2} | V _{IN} = 5.0 V, Ic = 0.2 A | | | 0.3 | V |
| Low level input voltage | VIL Note 2 | $V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$ | | | 0.3 | V |
| Input resistance | R1 | | 7 | 10 | 13 | kΩ |
| E-to-B resistance | R₂ | | 7 | 10 | 13 | kΩ |

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

 $R_1 = 470 \Omega$

0.8

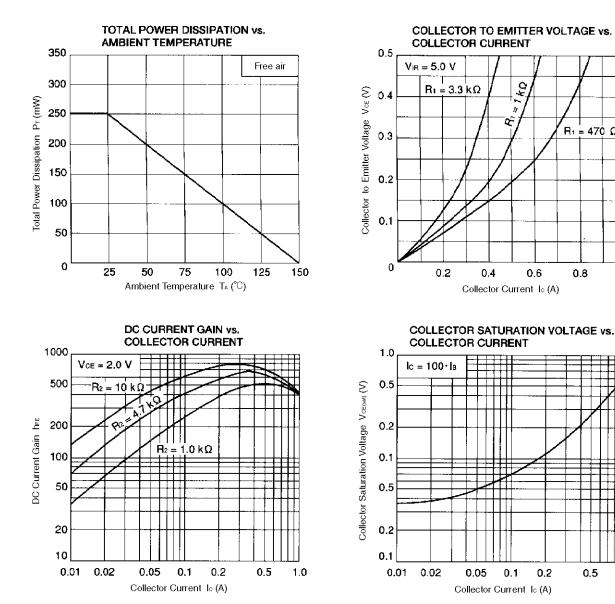
0.5

1.0

1.0

Phase-out/Discontinued

TYPICAL CHARACTERISTICS (Ta = 25°C)



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